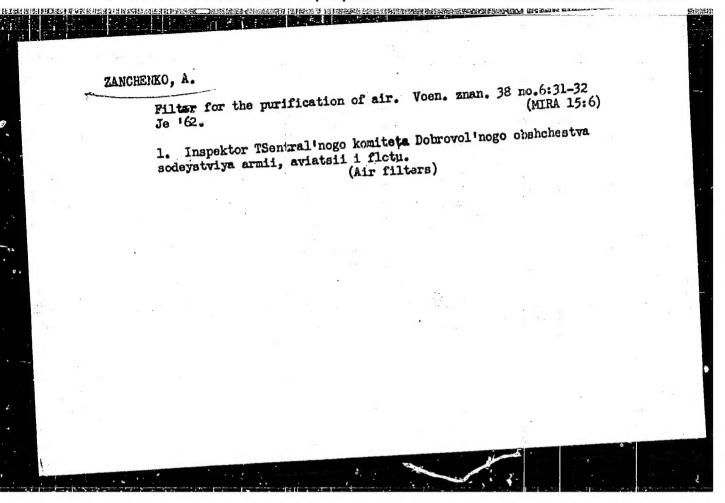
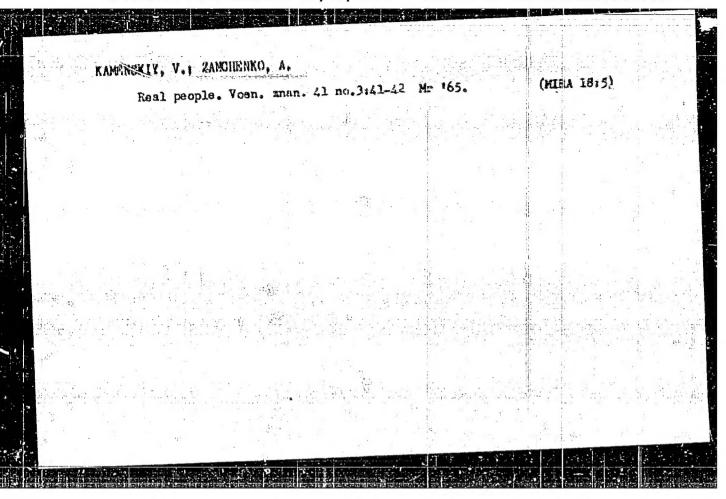


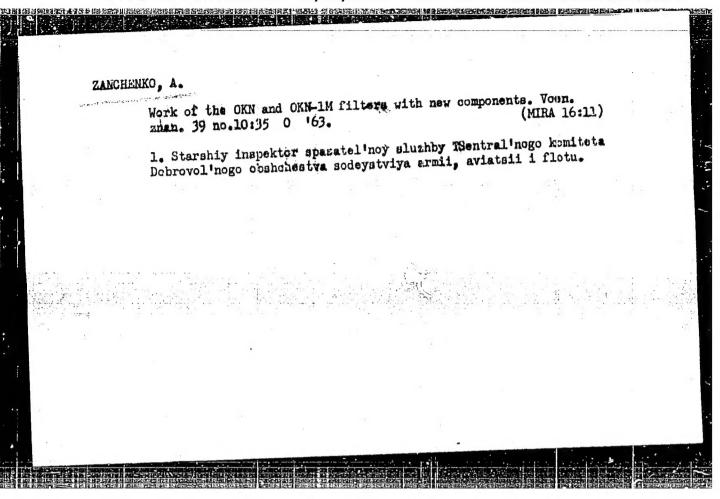
ZANDERG, J.

"Assuring housing for brigades in collective farms." p.10 (MECHANIZATOR ROLNICTWA, Vol.2, no.3, March 1953 Warszawa, Poland)

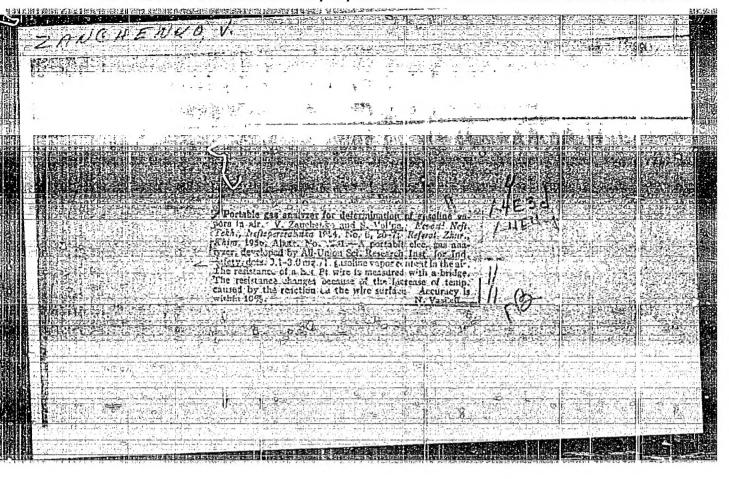
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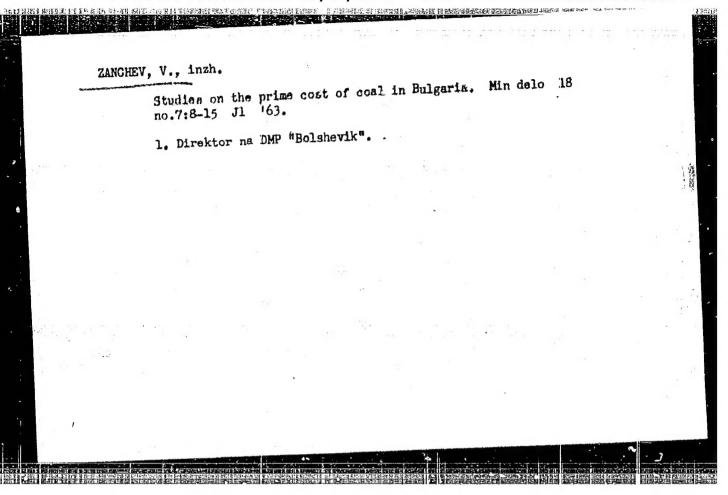


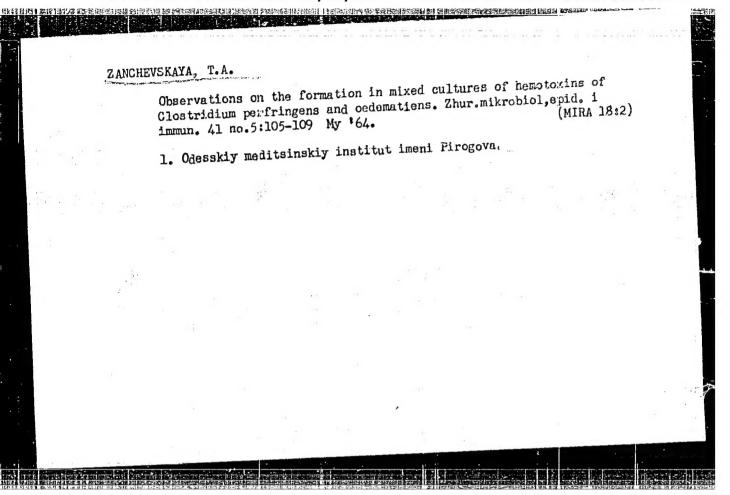




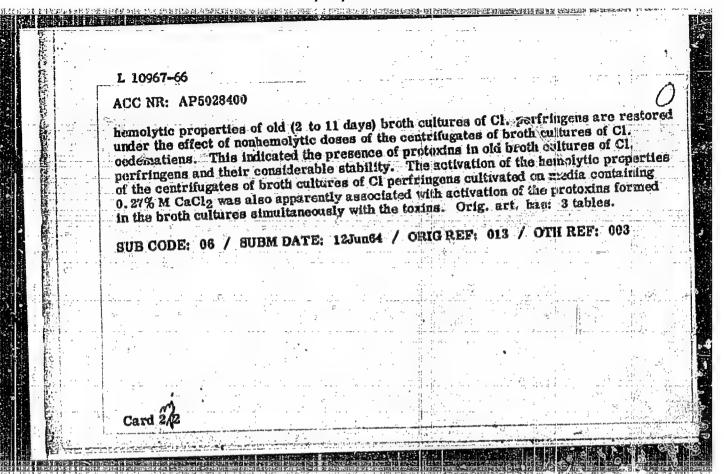
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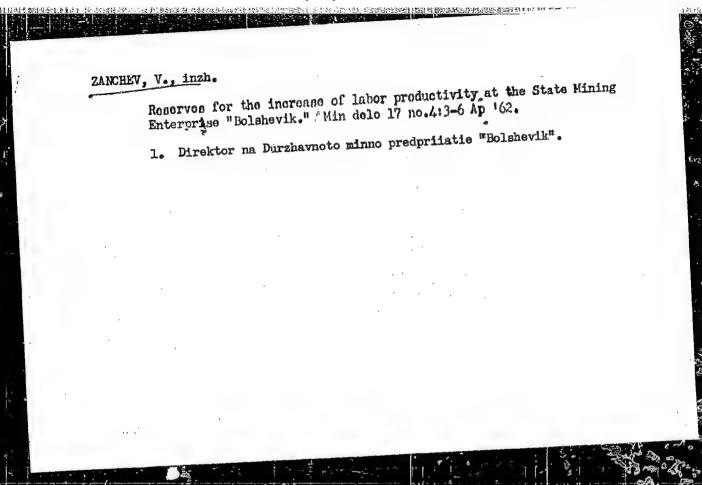


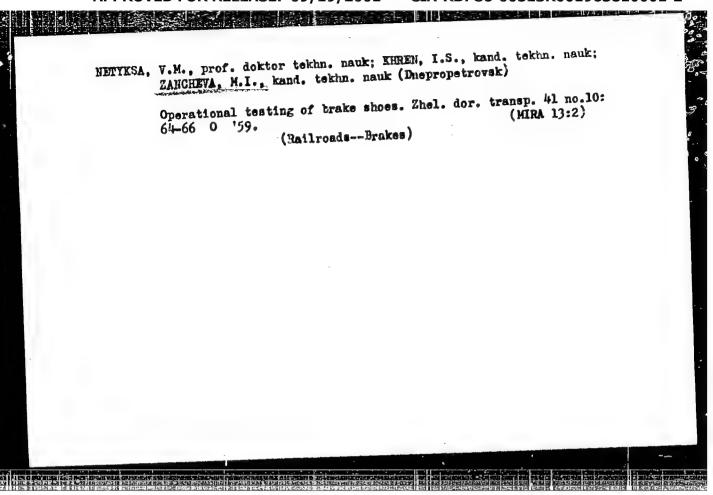


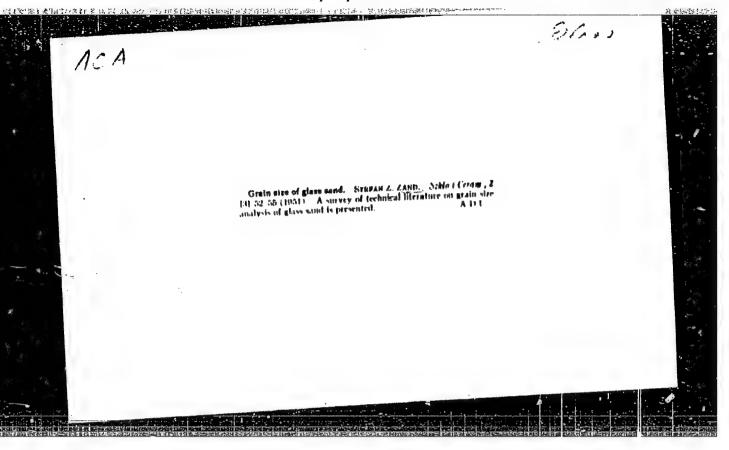


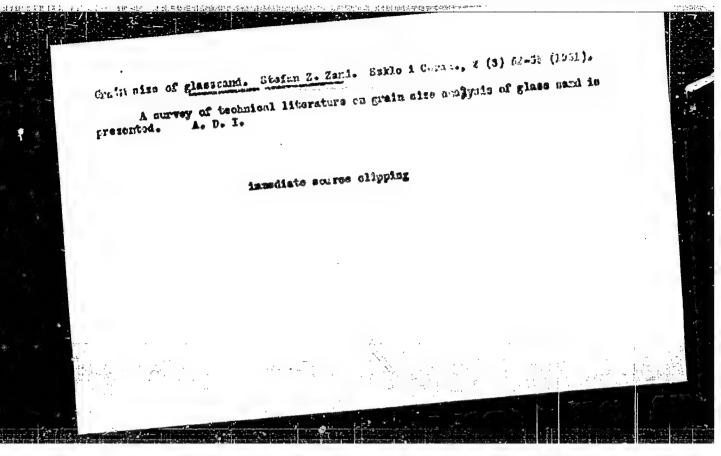
	L 10967-66 EWT(1)/EWA(1)/EWA(b)-2 JK CC NR: AP5028400 SOURCE CODE: UR/0016/65/000/009/0115/0120
A	TUTHOR: Zanchevskaya, T.A. 65
_	Odesskiy medical Institute im. N.I. Pirogov (Odesskiy meditsinskiy institut)
	PITLE: Factors causing the restoration of toxic properties in centrifugates of e <u>legatridiu</u> perfringens cultures which have lost their toxicity
	SOURCE: Zhurnal mikrobiologii, epidemiologii i immunobiologii, no. 9, 1965, 115-120
	A BCTPACT. The author performed a series of experiments to check the preservation
	period of protoxins (mactive toxina) and the second properties. The using for this purpose strain No. 39 which does not have hemolytic properties. The using for this purpose strain No. 39 which does not have culture of this strain varied using for this purpose of the centrifugate of a 20-hour culture of this strain varied have cultures did not have
	within 0.5 - 0.4 mi. The centringstone which within 0.5 - 0.4 mi. The centringstone which properties. To establish whether protoxins were in these centringstone, the properties of a
	author mixed them in declare of Cl. oedematicans (strain No. 4) which had property centrifugate of a broth culture of Cl. perfringens. It was found that the
	markedly potentiating the action of the total UDC: 576.851.655.097.21 Card 1/2
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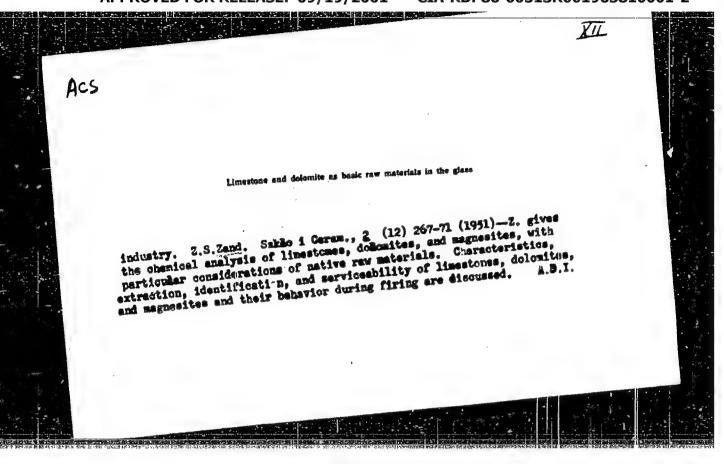


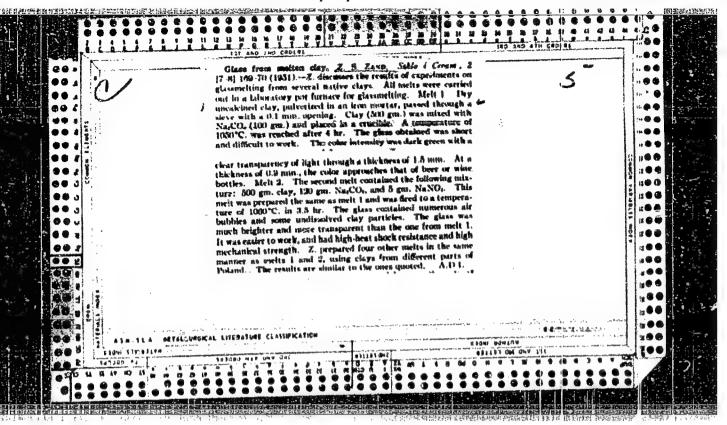












ZANDA, VACLAV FRANTISEK.

GEOGRAPHY & GEOLOGY

ZANDA, VACLAV FRANTISEK. Karlovy Vary; Stadtfuhrer. Praha, Sportovni a turisticke nakl., 1958. 120 p.

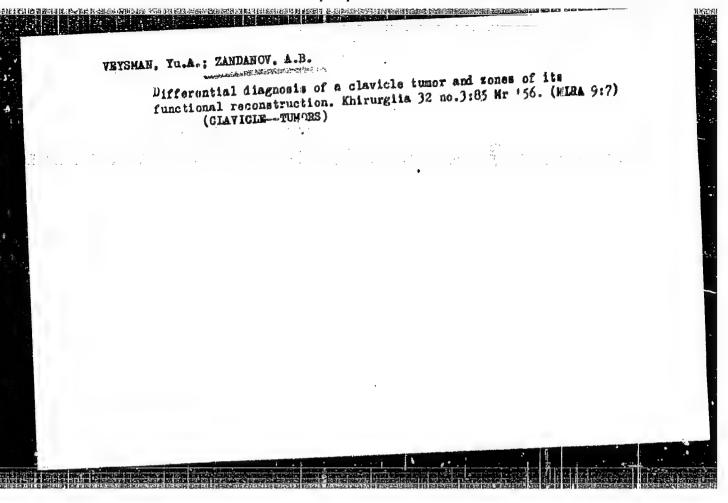
Monthly List of East European Accessions (EEAI) LC, Vol. 8, No.5
May 1959, Unclass.

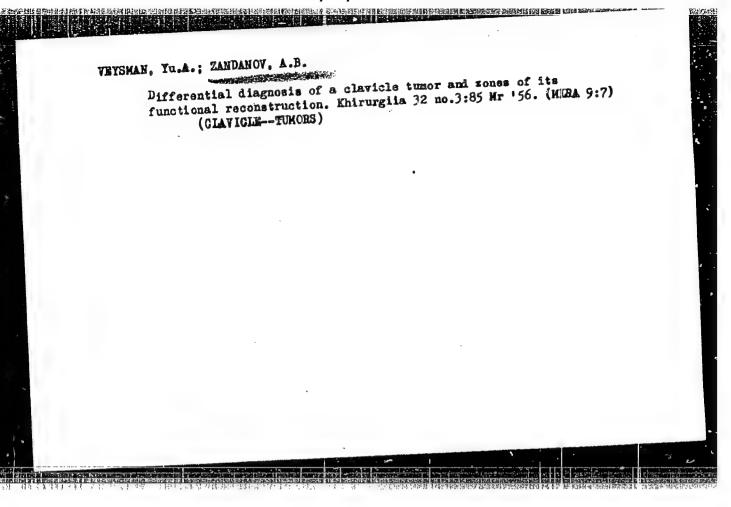
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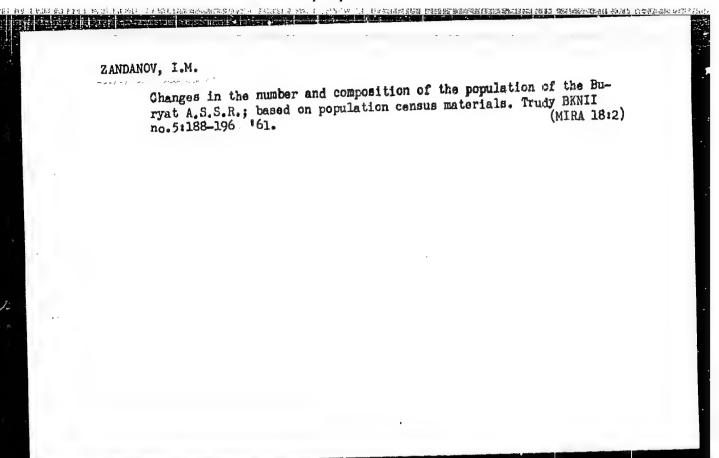
ZANDA, Vaclay Frantisek

Karlovarsko. Oblastni turisticky pruvodce cis. 2. (Karlovy Vary Area; Regional Tourist Guide, No. 2. 1st ed. illus., maps, bibl., indexes) Prague, Sportovni a turisticke nakl., 1957. 129 p.

Bibliograficky katalog, CSR, Ceske knihy, No. 32. 17 Sept 57. p. 677.







自自从形式上的"2007年12分子以后,我们可以在11万元人从中的中国人家的东西的 自用的经验处理的的的现在分词,但是他们的特别的现在,但是中国的特别的。

MADNAYEV, Gombo Shirapovich; ZANDANOV, I.M., otv. red.;

[Ways of developing the light and food industries of the Buryat A.S.S.R.] Puti razvitiia legkoi i pishchevoi promyshlennosti Buriatskoi ASSR. Ulan-Ude, Buriatskoe knizhnoe izd-vo, 1965. 124 p. (MIRA 18:8)

ACCESSION NR: AT4042301

8/0000/63/003/000/0243/0253

AUTHOR: Grinberga, D.A., Zandart, Ya, Ya.; Zander, Yu. K., Laumanis, I. Ya

TITLE: Investigation of an experimental DC conduction pump

SOURCE: Soveshchaniye po teoreticheskoy i prikladnoy magnitnoy gidrodinamike. 3d, Riga, 1962. Veprosy* magnitnoy gidrodinamiki (Problems in magnetic hydrodynamics); doklady* soveshchaniya, v. 3. Riga, Izd-vo AN LatSSR, 1963, 243-253

TOPIC TAGS: conduction pump, direct current pump, pump testing

ABSTRACT: The authors have designed the experimental mercury system shown in Figure 1 of the Enclosure for the purpose of verifying the theory of DC compensation-type conduction pumps. The pump model to be tested 5 (Figure 1) is connected in series with pump 1 through valve 4, connecting tubes 2 and Venturi tube 7. The purpose of pump 1 is to compensate for the loss of pressure in the internal hydraulic circuit. The useful pressure, developed by the test pump 5 in the internal hydraulic circuit, is measured by means of mercury manometers 6, while the speed of the liquid metal is measured (in order to determine the productivity Q) by means of the Venturi tube. The authors note that the channel and the windings of the magnet of the pump to be tested

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ACCESSION NR: AT4042301

can be connected both in series and independently. Graphs are presented illustrating the P_RQ and \mathcal{N}_RQ characteristics of a test model of a compensating pump with series and with independent excitation. Formulas are given for the maximum values of the pressure p_{1m} and productivity Q. There is a discussion of the voltage U in the channel as a function of the productivity Q. A method is proposed for dividing the boundary current I, into the so-called intrapolar current I and extrapolar current I. For the purpose of comparing the derived experimental data with the theory, the authors employed the calculation method proposed by Watt (Watt, D. A., O'Connor, R. J., and Holiand E. Tests on an experimental d-c pump for liquid metals. Harwell, 1957; Watt, D. A. Analysis of experimental d-c pump performance and theory of design, Harwell, 1957). The results are analyzed from the point of view of agreement or lack of agreement between experimental and theoretical information. "The work was carried out under the supervision of Yu. A. Birzvalk (Cand. in the Tech. Soi.). Orig. art. has: 5 figures and 17 formulas.

ASSOCIATION: none

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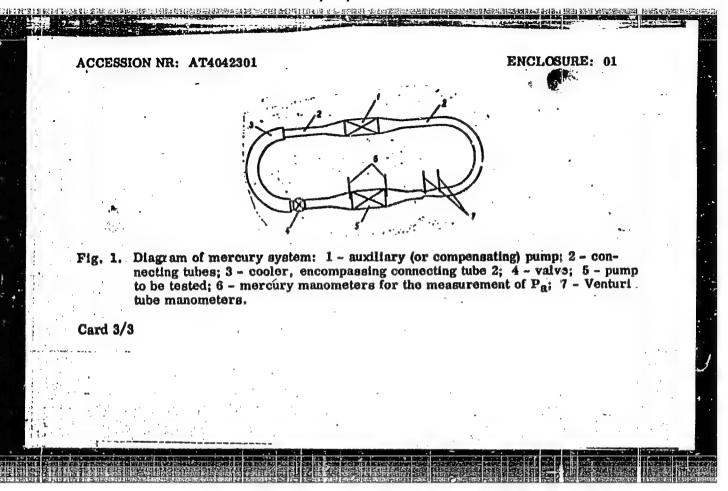
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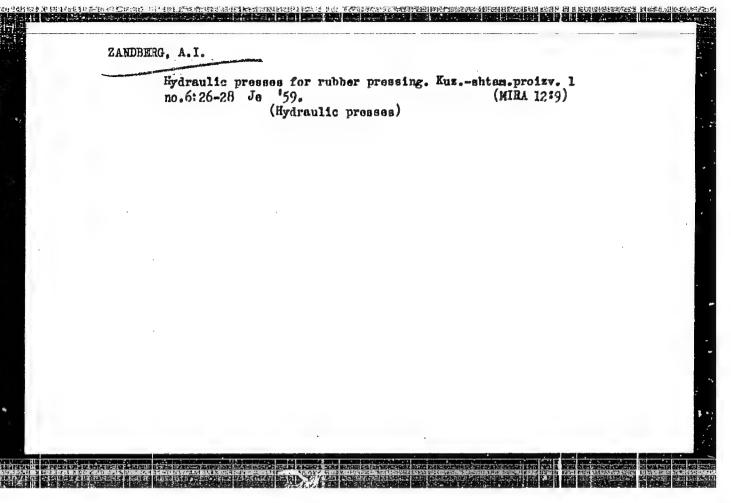
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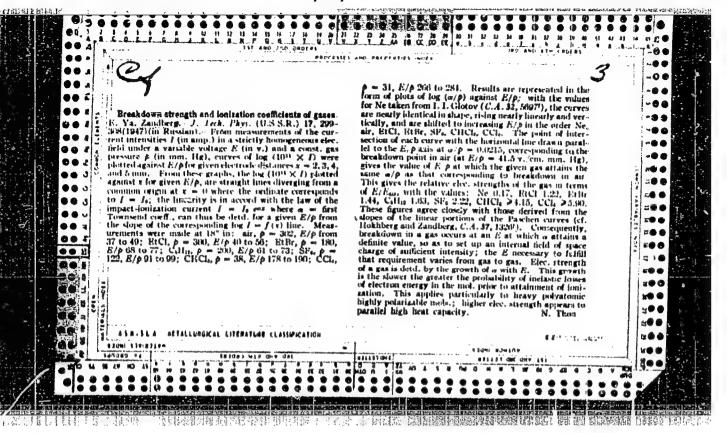


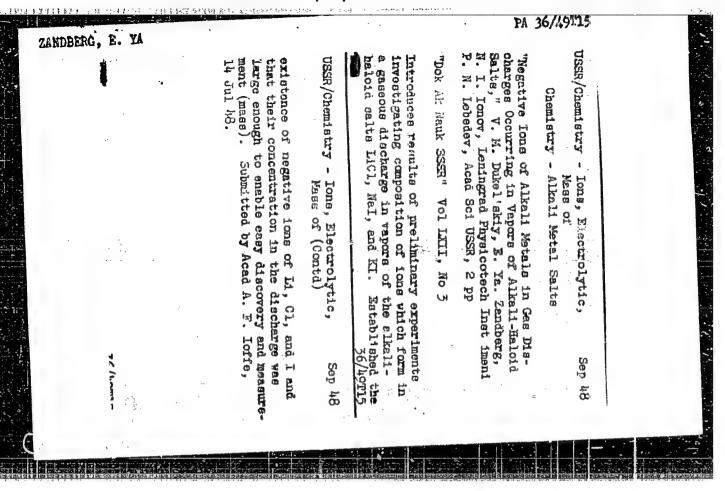


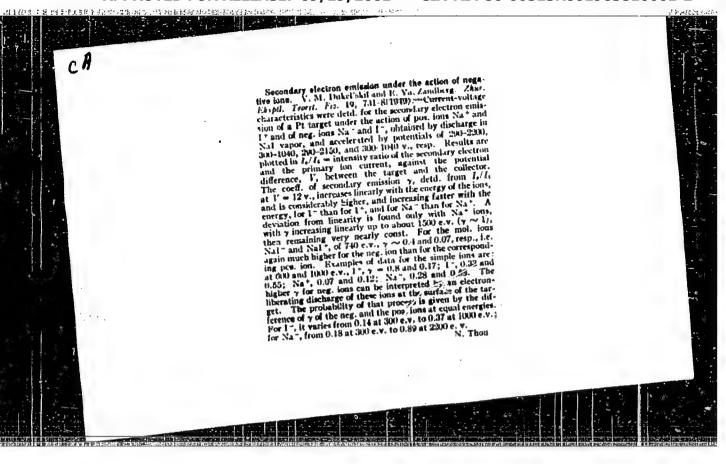
GOKHBERG, B. M., and ZANDBERG, E. Ya.

Mbr., Leningrad Physical Technical Institute, abad. Sci., (-1966-)

"Ionization of Gases and Their Breakdown Strength," Dok. AN, 53, No. 6, 1946







ZANDBERG, E. YA.

Leningrad Physico-Technical Inst., Dept. Physico-Math. Sci., Acad. Sci., (Mor., Roentgenography Lab., -1940-; Mbr., -1942-c49-).

"Megative Alkalina Ions in Gas Discharge in Vapors of Alkali Halide Salta,"

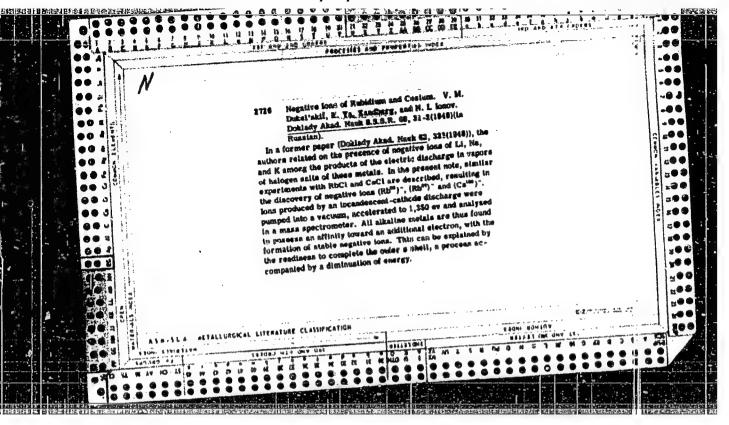
ibid., 62, No. 3, 1943;

"Negative Ions of Rubidium and Cosium," Ibid., 68, No. 1, 1949;

"The Problem of Secondary Electron Emission under the Action of Megative Ions,"

Zhur. Eksper. i Teoret. Fiz., 19, No. 8, 1949.

(1907515).



ZANDBERG, YA.

PA 169T93

USSR/Physics - Gaseous Discharge Ions, Negative

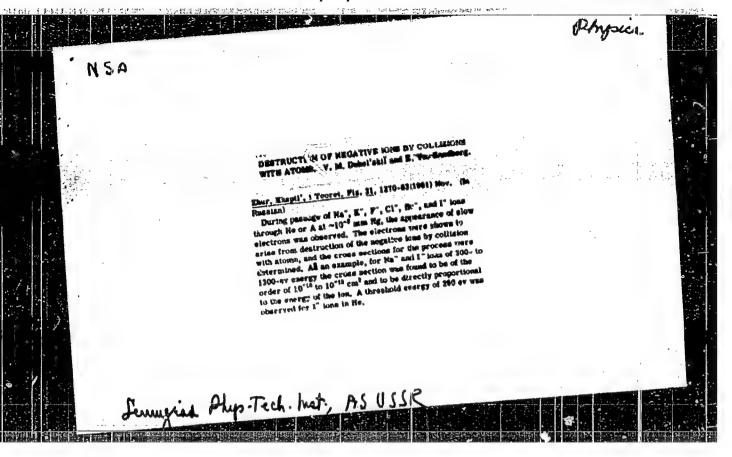
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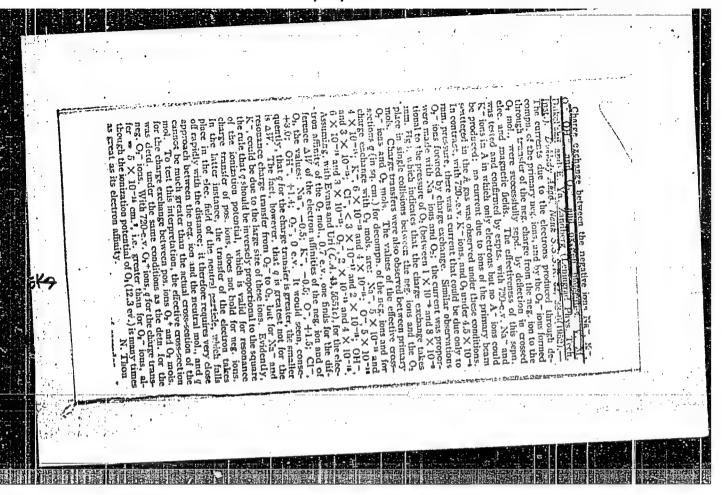
"Megative Ions in a Gaseous Discharge in Vapors of Halide Salts of Alkali and Alkali-Earth Metals," V. M. Dukel'skiy, E. Ya. Zaiziberg, N. I. Ionov, Leningrad Physicotech Inst. Acad Sci USSR

"Zhur Eksper i Tegret Fiz" Vol XX, No 10, pp 877-885.

Mass-spectroscopic analysis of composition of negative ions occurring in gaseous discharges in vapors of subject salts: Establishes existence of Li-, Na-, K-, Rb-, Cs-. Ions Mg- and Ca- in discharges in vapors of MgCl₂ and CaCl₂ are not observed. Mcle-cular negative ions of type MeX- and MeX₂ are observed in the case of alkali halide cular negative ions of type MeX-, and MeX₂, and MeX₃ for CaCl₂ and MgCl₂ also are observed. Negative atomic ions of Ag are observed in discharges in vapors of AgI. Submitted

PA 169193.

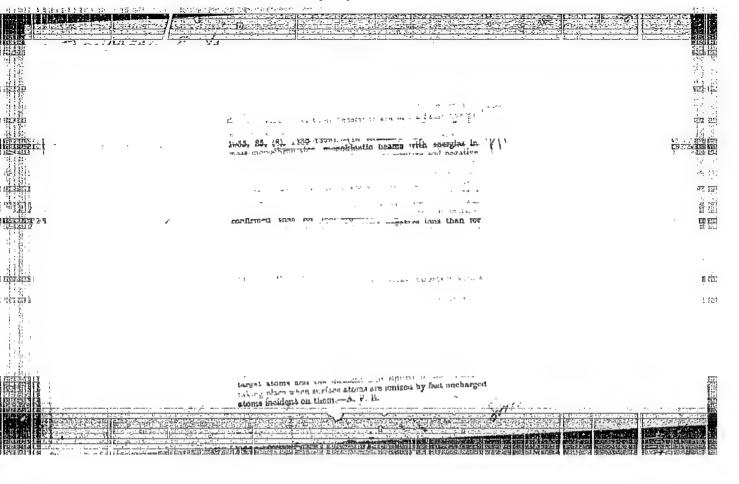




235199 ZANDBERG, E. Ya. USSR/Physics - Negative Arsenic Ions "Negative Ions of Arsenic, Phosphorus, Sulfur, and Thallium," V. M. Dukel'skiy, E. Ya. Zandberg "Dok Ak Nauk SSSR" Vol 86, No 2, pp 263-265 Continuation of the study of the ability of atoms and mols to add an addul electron and to be converted into free neg ions ("Zhur Eksper i Teoret Fiz" 20, 877 (1950); "Dok Ak Nauk GSSR" Vol 81, 767, 1951), Here investigate the compn of ions that arise in a gaseous discharge in nitrogen and ammonia, and also in vapors of arsenic, phosphorus, sulfur, and halide salts of thallium. Submitted by Acad A. F. Ioffe 5 Jul 52.

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USSR/Physics - Nuclear physics Card 1/ Pub. 22 - 17/63 Dukel'skiy, V.M., and Zandberg, E.Ya. Authors WATER TRANSPORTED FOR t Dissociation of molecular negative ions when colliding with atoms Title Periodical : Dok. AN SSSR 99/6, 947-950, Dec 21, 1954 Experiments, intended to reveal the processes which accompany collisions of negative ions with atoms of gases (He and Ar), are described. Ions of Abstract the following substances were used in the experiments: Teg, Sbg, Sbg, Bi2, NaJ, and NaJ2. The formation of secondary ions and the dissociation of negative ions with electrons were only observed. Four references; 2-USSR (1915-1953). Graph; Diagram. The Leningrad Physico-Technical Institute of the Acad. of Scs. of the Institution: Academician A.N. Terenin, July 12, 1954 Presented by:



E. YH. ZANdbERG Zandberg, E. Ya. AUTHOR:

57-11-20/33

TITLE:

The Surface Ionization of Potassium Atoms and KCl- and CaCl-Molecules in Electric Fields up to 2 MV/cm on Tungsten (Poverkhnostnaya ionizatsiya atomov kaliya i melekul KCl i CsC). v elektricheskikh polyakh do 2 MV/cm na vol'frame)

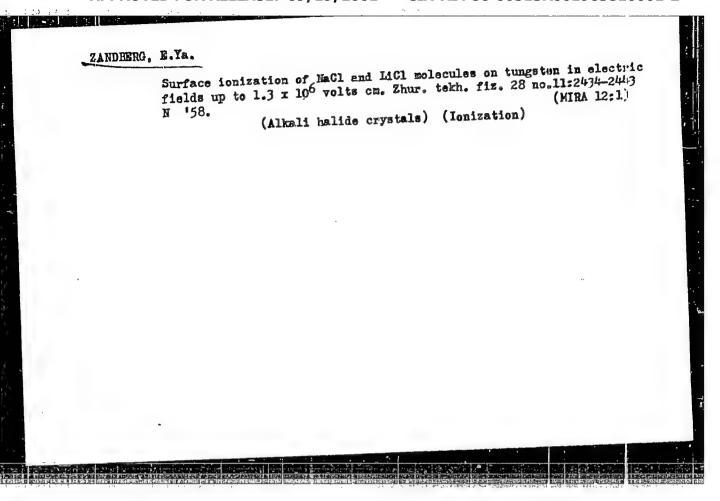
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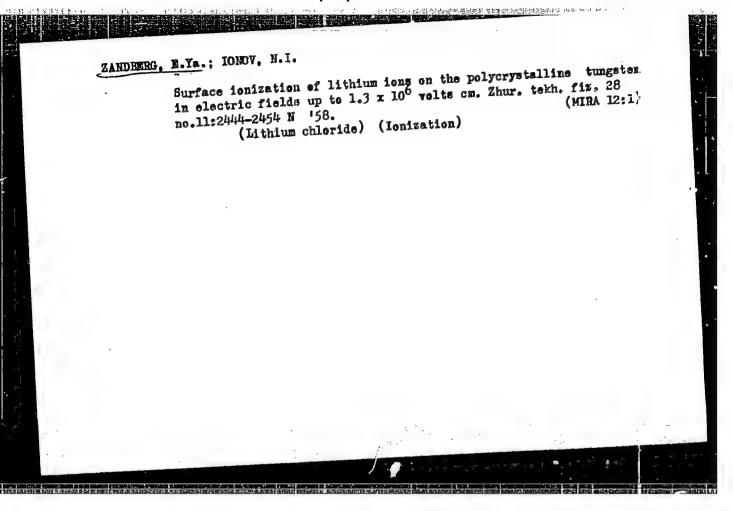
Zhurnal Tekhn. Fiz., 1957, Vol. 27, Nr 11, pp. 2583-2594 (USSR)

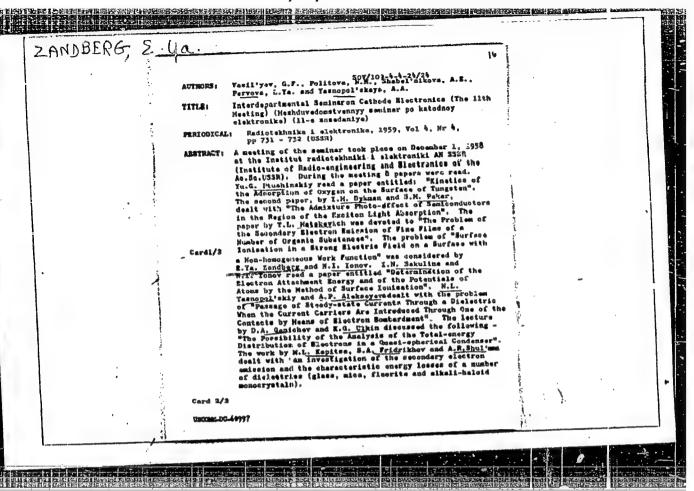
ABSTRACT:

The present work is the direct continuation of that of Ionov, N. I. (Zhunral Tekhn. Fiz., 1956, Vol. 26, p. 2200). The displacement of the temperature threshold of the surface ionization of potassium atoms and of KCl- as well as of CsCl-molecules in dependence on the intensity of stress of the electric field in a cylindrical condenser with tungsten wire was investigated. In the case of the surface ionization of potassium atoms on tungsten in a field of ~2MV/cm this displacement into the area of low temperatures amounted to ~1700. To the same degree of ionization of K, Kol and CsCl within the temperature ranges in the various electric fields that were situated in the near of the threshold, temperatures corresponded, which, with the increase of the voltage of the field E on the thread, decrease proportional to YE. This coincides with the assumption that the evaporation operation of the adsorption atoms, which are mainly in ion-state, decreases in the presence of a strong electric field. In the case

Card 1/2







SOV/53-67-4-2/7 28(8) Zandberg, E. Ya., Ionov, N. I. : EROHTUA Surface Ionization (Poverkhnostnaya ionizatsiya) Uspekhi fizicheskikh nauk, 1959, Vol 67, Nr 4, pp 581-623 (USSR) TITLE: PERIODICAL: The authors give a survey of the phenomena of surface ionization taking special ascount of the theory. The following ABSTRACT: subjects are dealt with by the individual parts: I. Surface ionization with formation of positive ions in general representation; 1) emission formulas for a homogeneous surface without electric field, 2) emission formulas for a homogeneous surface with electric field, 3) surface ionization of atoms on semiconductors, 4) emission formulas for an inhomogeneous surface, 5) thresholds in the temperature-dependence of the surface ionization current. In part II the results obtained by a number of experimental works on positive surface ionization are compiled. Individual chapters deal with the following subjects: 6) The methods of investigating positive surface ionization. 7) The positive surface ionization of Cs-, Rb., and K-atoms on tungsten in weak electric fields. 8) The positive surface ionization of Na- and Li-atoms on tungsten in weak fields. 9) The positive surface ionization of alkali-halide Card 1/3

Surface Ionization

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salts on tungsten weak fields. 10) The positive surface ichization of alkali vietal atoms and molecules of alkalizalide salts on platinum in weak fields. 11) The surface ionization of other elements and other compounds in weak fields (on tungsten). 12) The investigation of the energy distribution of positive ions (Fig 14). 13) The positive surface ionization in electric fields (104 v/cm). 14) The determination of the isothermal evaporation heats of ions and atoms on the surface. 15) Measurement of the ionization coefficient of K- and W-s.toms. In part III of the paper the surface ionization with formation of negative ions is discussed in short. Individual chapters deal with the following: 16) The negative surface ionization on homogeneous surfaces. 17) Negative surface ionization on spotted surfaces. (3) Discussion of investigation methods. 19) Measurement of the temperature dependence of the negative ion current (Figs 21-23). 20) Determination of the energy of affinity to the electron by the method of negative surface ionization (Tables 1 and 2). - The paper gives a detailed description of the problems, methods, and results connected with the phonomena of surface ionization. The material was obtained solely from published works. The paper is of great value for scientists dealing with these problems on account of its clearness, its wealth of material, and its comprehensive

Card 2/3

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Surface Ionization

account of publications. There are 23 figures, 2 tables, and
113 references, 66 of which are Soviet.

Card 3/3

"APPROVED FOR RELEASE: 09/19/2001

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ZANdbELG, t. YA

s/048/60/024/05/01/017 B019/B067

9,3120

AUTHOR:

Zandberg, E. Ya.

TITLE:

Influence Exercised by an Electric Field on the Temperature Threshold of the Occurrence of Positive Ions

in Surface Ionization of Atoms A

PERIODICAL:

Izvestiya Akademii nauk SSSR. Seriya fizicheskaya,

1960, Vol. 24, No. 6, pp. 629-634

TEXT: This paper is the reproduction of a lecture delivered at the 9th All-Union Conference on Cathode Electronics from October 21 to 28, 1959 in Moscow. The ionization of a surface under the action of an electric field is investigated, which sucks off the produced ions at temperatures below the threshold temperature, Formula (1) is given, which describes the flux n of atoms toward the surface in the steady case. This formula contains corrections for the electric field which has the field strength E on the surface. If only a field with a few megavolts per om 18 dealt with and if only such metal atom pairs are studied with which the threshold range of temperatures is distinctly marked, formula (1) can be

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82156 8/048/60/004/06/01/017 Influence Exercised by an Electric Field on B019/B067 the Temperature Threshold of the Occurrence of Positive Ions in Surface Ionization of Atoms replaced by formula (3): $n_0 \approx NCexp\left(-(1 + \psi)/kT\right)$, where N is the atomic concentration on the surface and l the isothermal heat of evaporation of ions. W concerns the correction for the electric fielt. The author then derives the expression (7) for $\frac{1}{2}$, and thus obtain: formula (8): $\frac{1}{2}$ NCexp $\left\{-\left(1 + \epsilon\right) \in \mathbb{R} + \epsilon \in \mathbb{R}_{cr}\right) / kT\right\}$ for (3). In this formula C is a coefficient depending weakly on T, x is the critical distance of the charge exchange of the atoms adsorbed on the surface. E as the charge of the lone. Some formulas for x and \(\frac{1}{max} \) are derived, and the determination of x_{CT} is dealt with. Condition (13) is given from (8) for the constant flux which for a linear dependence of the form T=f (\sqrt{E}) assumes the shape (14) const = $(1 + \epsilon \sqrt{\epsilon E})/kT$. Therefrom a new possibility is obtained for determining the heat of evaporation of ions when is smaller than ? (V., the ionization potential of atoms). Experimense were made on the temperature dependence of the nursuce ionization in Card 2/3

Influence havroised by an Electric Field on the Temperature Threshold of the Occurrence of Positive Ione in Surface Ionization of Atoms 8/048/60/024/06/01/017 B019/B067

electric fields with field strengths of up to 7 Mv.cm⁻¹. The functions $T = f(\sqrt{E})$ shown in Figs. 4 and 5 were constructed on the basis of these results. From these diagrams, x_{cr} could be determined for K^{\dagger} ions according to formula (13). The author determined $x_{cr} < 4$ A. With the less accurate formula (12) 7 A were obtained. The heat of evaporation calculated

rate formula (12) 7 A were obtained. The heat of evaporation calculated according to formula (15) on the basis of the results obtained for K⁺ ions on tungsten is found to be 2.2 to 2.3 ev. The method described here allows an evaluation of the character of the dependence of heat of evaporation of ions on the degree of coating of the surface by ionizable atoms. The author thanks if. I lonov for interesting discussions. There are 6 figures and 9 references: 8 Soviet and 1 British.

ASSOCIATION:

Leningradskiy fiziko-tekhnicheskiy institut Akademii

nauk SSSR

Leningrad Physicotechnical Institute of the Academy of

Sciences, USSR)

Card 3/3

24,2100,24,7400

77314 sov/57-30-2-11/18

AUTHOR:

Zandberg, E. Ya

TITLE:

9

Influence of the Electric Field on the Temperature Threshold for the Positive Ion Appearance During

Surface Ionization of Atoms

PERIODICAL:

Zhurnal tekhnicheskoy fiziki, 1960, Vol 30, Nr 2,

pp 205-215 (USSR)

ABSTRACT:

The prime goal of the author was to obtain an estimate for the critical distance \mathbf{x}_{kp} of the charge-exchange

phenomenon. In absence of this critical distance, the ions during surface ionization would be formed on the surface of the metal with a definite heat of evaporation. If one would then add an outside applied field, the heat of evaporation of the ions would in this simplified case vary as e yee, following the law of Schottky as in the case of thermoelectron emission. In case of significant values of x_{kp} one would expect

a measurable deviation from Schottky law, and since the heat of evaporation is proportional to the temperature

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Influence of the Electric Field on the Temperature Threshold for the Positive Ion Appearance During Surface Ionization of Atoms

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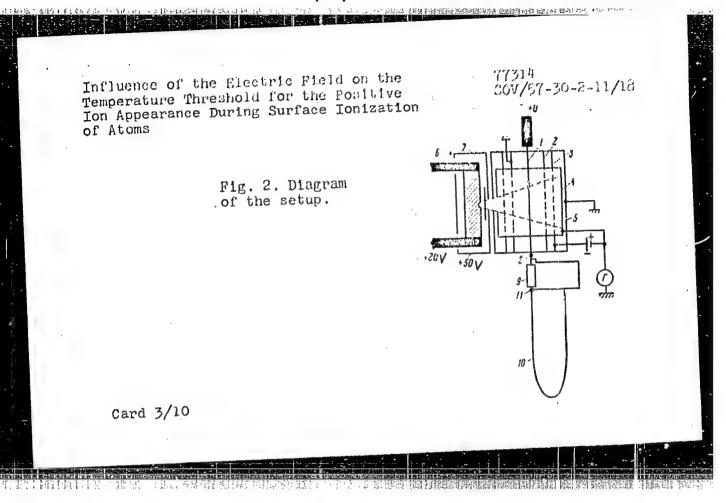
threshold for the positive ion emission, the author proceeded to measure these thresholds. The present paper is essentially a continuation of previous investigations by the author (ZhTF, XXVII, 2583, 1957), gations by the author (ZhTF, XXVII, 2583, 1957), extended in the region of higher field intensities with extended in better estimates for the x_{kp} value.

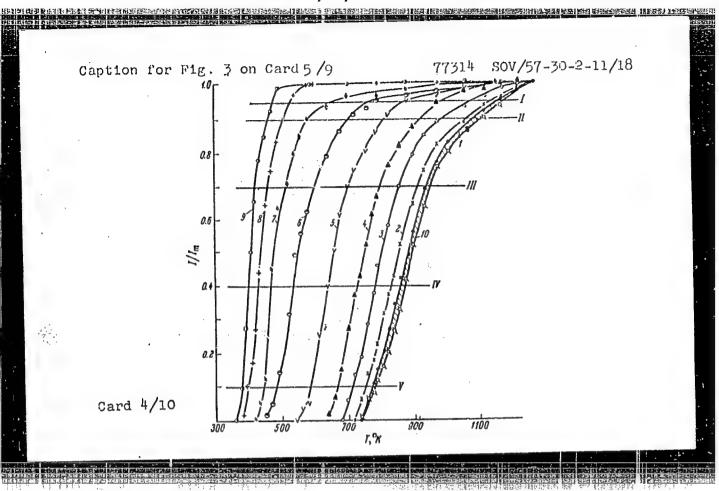
The details of the experimental setup were described earlier (ZhTF, XXVIII, 2434, 1958). This diagram is on Fig. 2. The filament (1) was here thinner than in previous experiments in order to achieve surface fields up to 7 mv/cm. It is surrounded by a system of cylinup to 7 mv/cm. It is surrounded by a system of cylinder (2), (3), (4), and (5), of which (4) is an ion collector, (2) and (3)-transparent grid cylinders suppressing the secondary collector currents, (5)-a shield. Evaporator (6) and (7) is identical to those used previously. The filament continued through the eyelet previously. The filament continued through the eyelet (8), 0.5 mm in diameter and was stretched by means of the adjustable weight (9). The loop (11) prevented vibrations and guided the copper contact (10).

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Influence of the Electric Field on the Temperature Threshold for the Fositive Ion Appearance During Surface Ionization of Atoms

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Fig. 3. Ionization curves of CaCl for various E: (1) E = 55.2 ky/cm; (2) E = 105.6 ky/cm; (3) E = 352 ky/cm; (4) E = 704 ky/cm; (5) E = 1.76 my/cm; (6) E = 2.81 my/cm; (7) E = 4.22 my/cm; (8) E = 5.63 my/cm; (9) E = 7.04 my/cm; (10) E = 55.2 ky/cm at end of measurements.

Filaments of 8 / In diameter could be heated up to $T=1500^{\circ}$ K. A TSVL-100 pump produced a 2 to $3\cdot 10^{-7}$ tor vacuum. Temperatures were measured by means of a microoptical pyrometer. The author investigated the sufface ionization of K atoms and CsCl molecules. Typical results are on Fig. 3. Here I - ion current at temperature T, I_m - saturation current on the plateau of the curve. The author notes that at E=7 my/cm this saturation value is reached at approximately $T=1000^{\circ}$ K, which indicates that the CsCl molecules are

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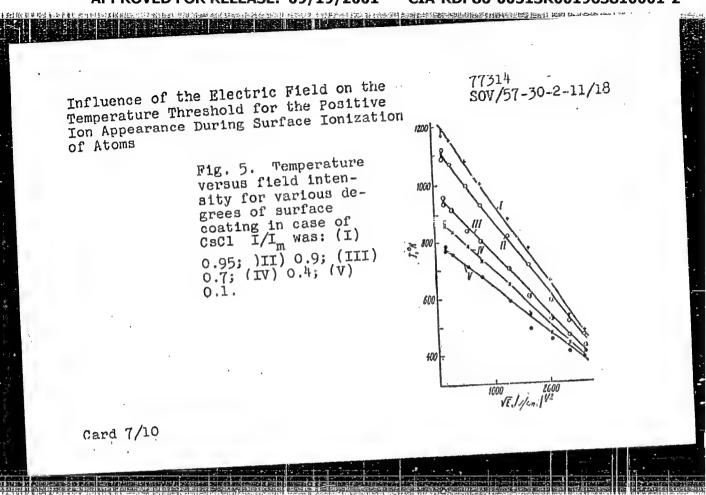
Influence of the Electric Field on the Temperature Threshold for the Positive Ion Appearance During Surface Ionization of Atoms

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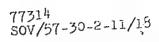
practically dissociated on the tungsten surface at such a low temperature that the process is apparently of a catalytic nature. The experimental curves served to establish a second set of curves, shown on Fig. 5. Experimental points lie almost along straight lines. Experimental points lie almost along straight lines. According to the theory, however, there should be a departure from a straight line behavior proportional departure from a straight line behavior proportional to the size of $x_{\rm kp}$ since $x_{\rm kp}$ enters the formula for the correction in the heat of evaporation Δ in

 $\Delta I_{+} = e\sqrt{eE} - eEx_{\rm sp.}, \qquad (5)$

The theoretical curves for different values of $x_{\rm kp}$ are plotted on Fig. 7. Comparing Fig. 5 and 7 the author concluded that $x_{\rm kp} \le h$ A, contrary to the theoretical computations by Veksler (DAN Uzb. SSR. 5, 5, 1,555). He also concludes that the Schottky expression for the interaction force between the charged particle and the conducting surface holds up to distances



Influence of the Electric Field on the Temperature Threshold for the Positive Ion Appearance During Surface Ionization of Atoms



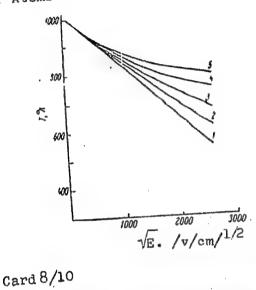


Fig. 7. Relationship
$$T = f(\sqrt{E}) \text{ for } \Delta l_{+} = 0;$$

$$= e \sqrt{eE - eEX_{kp}} \cdot (1) x_{kp} = 0;$$

$$(2) x_{kp} = 2 A; (3) x_{kp} = 4 A;$$

$$(4) x_{kp} = 6 A; (5) x_{kp} = 8 A.$$

Influence of the Electric Field on the Temperature Threshold for the Positive Ion Appearance During Surface Ionization of Atoms 77314 SOV/57-30-2-11/18

of 7 A. This is significantly less than what can be obtained in tests with the thermoelectronic emission in strong electric fields. Since the threshold shift is related to the heat of evaporation of ions, the author was able to derive an equation for this heat 1, using two points on the

 $T = f(\sqrt{E})$ curves:

$$l_{+} = \varepsilon \sqrt{\varepsilon} \frac{T_2 \sqrt{E_1 - T_1} \sqrt{E_C}}{T_2 - T_1}$$
 (11)

In the case of K, l_+ came out to be about 2.2 ev, and quite independent on the degree of surface covering. This is in fair agreement with results obtained by other researchers. This l_+ value can in turn be used for estimating the lower limit of x_{kp} , and the author obtained $x_{kp} \longrightarrow 1.8$ to 1.5 A. In

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Influence of the Electric Field on the Temperature Threshold for the Positive Ion Appearance During Surface Ionization of Atoms

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an analogous manner 1, for Cs tis between 1.6 and 1.8 ev which correspond to $x_{kp} \ge 2$ to 2.2 A. In this case 1, depended on the degree of surface covering due probably to a significant influence of the covering on the adsorption of Cs atoms. Professor Ionov discussed many times the questions presented in this paper. There are 7 figures; and 15 references, 13 Soviet, 2 U.K. The U.K. references are: P. B. Moon a. M. L. Oliphant, Proc. Roy. Soc., A137, 463, 1932; R. C. Evans. Proc. Roy. Soc., A139, 604, 1933. Physico-Technical Institute AS USSR, Leningrad (Fiziko-

ASSOCIATION:

tekhnicheskiy institut AN SSSR, Leningrad)

SUBMITTED:

June 15, 1959

Card 10/10

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s/057/60/030/010/011/019 B013/B063

26.1420

Zandberg, E. Ya. AUTHOR:

Surface Ionization of Indium and Thallium Atoms on Poly-

crystalline Tungsten in Electric Fields up to 2 mv/cm TITLE:

PERIODICAL: Zhurnal tekhnicheskoy fiziki, 1960, Vol. 30, No. 30,

pp. 1215 - 1221

TEXT: Formulas for emission from inhomogeneous surfaces are given in Refs. 2 and 3 where three cases of ionization were treated. Now, the author studies the case $\mathcal{E}(V-\phi_{k \text{ max}}-\psi)\gg kT$ (1) with the help of the method described in Ref.1. & - ion charge, V - ionization potential of the atom, ψ_k - local value of the work function of the surface, ψ - correction to the work function for the presence of an electric field on the surface of an electric field by which the ions are sucked off; $\psi = \sqrt{\epsilon E}$ for E~1 mv/cm. The experimental device is schematically shown in Fig.1. The author describes the surface ionization of indium atoms on polycrystalline tungsten between 1900 and 2500°K and at a field Cará 1/3

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Surface Ionization of Indium and Thallium 8/057/60/030/010/011/019
Atoms on Polycrystalline Tungeten in B013/B063
Electric Fields up to 2 mv/cm

strength of 30 kv/cm to 2.1 mv/cm on the surface. Fig. 3 indicates that the temperature dependence of the Int current on W fcllows an exponential law. The values for the actual work function ϕ^* determined from Fig. 3 and formula (9) are collected in a Table together with values of p* for Na and Li. The author attempted to measure the temperature dependence of the surface ionization of thallium on tungsten (Fig. 4). It may be assumed that within the limits of error the values of ψ^* obtained for In and Tl are in agreement. As has already been done in previcus papers, the measured values of E are compared with the values determined by means of the Schottky effect. It was found that the dependence of surface ionization on the electric field strength for surfaces having different work functions but all satisfying condition (1) follows the simple Schottky rule at all values of E. This is also in agreement with the theoretical predictions. All conclusions drawn from the theory of surface ionization on inhomogeneous surfaces were confirmed for (1) by the experiments with indium. Finally, an estimate is given of the maximum local work function of polycrystalline tungsten, which

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Surface Ionization of Indium and Thallium Atoms on Polycrystalline Tungsten in Electric Fields up to 2 mv/om S/057/60/030/010/011/019 B013/B063

approaches the results obtained by Smith (Ref.11) and Becker (Ref.9). The author thanks Professor N. I. Ionov for discussions. There are 6 figures, 1 table, and 12 references: 8 Soviet.

ASSOCIATION: Fiziko-tekhnicheskiy institut AN SSSR, Leningrad

(Institute of Physics and Technology AS USSR, Leningrad)

SUBMITTED: May 24, 1960

Card 3/3

ZANDBERG, E.Ya.; IONOV, M.I.

Fmission of positive molecular ions from heated surfaces in vacuum. Dokl. AM SCSR 141 no.1:139-142 M '61.

(MIRA 14:11)

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TITUE

34211 s/057/62/032/002/012/022 B124/B102 Zandberg, E. YE., Paleyev, V. I., and Tontegode, A. Ya. Dependence of the temperature threshold of surface ionization of cesium on tungsten on the cesium vapor tension Zhurnal tekhnicheskoy fiziki, v. 32, no. 2, 1962, 208 - 213 TEXT: A uniform electrode surface is considered which is only slightly PERIODICAL: covered by adsorbed atoms of the ionized element. - holds for the temperature dependence of the surface ionization current, where (is the ion charge, s is the ionizing surface area, A is the ratio of the statistical sums of ionic and atomic

states, n is the atomic flux per surface unit area per second, V is the ionization potential of the atom, y is the work function of the surface, and Wis the correction to f for the effect of an electric surface field. If V-P-V<0, the surface ionization current reaches its maximum; with T O and V + W - V > kT the current remains close to its maximum. Card 187

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Dependence of the ...

bd (Fig. 1) is termed the threshold region of the surface ionization curvi, and To is the threshold temperature. In the steady state, the flux of stms n incident on a homogeneous surface is $n = N \left[C \exp \frac{-(l_1 - l_1)}{kT} + D \exp \frac{-(l_0 + l_2)}{kT} \right] = 1$ $= N \left[C \exp{-\frac{l'_{+}}{kT}} + D \exp{-\frac{l'_{0}}{kT}} \right]^{[1]}.$

where N is the number of atoms per cm², C and D are constants slightly dependent on T, l_+ and l_- are the isothermal evaporation heats of ion and atom, respectively, in the absenct of an electric field near the surface, and ψ_1 and ψ_2 are correction factors for such a field (E). The surface ionization coefficient is $n = \frac{NC}{n} \exp\left(-\frac{1}{kT}\right)$. If $\ln n = C^1 + \ln \frac{N}{N_1} + \frac{N}{N_2}$

 $\frac{1!}{k}$ $\left(\frac{1}{T_{01}} - \frac{1}{T_{0}}\right)$ (6), where n_1 is a fixed flux of atoms, and T_{01} is the relevant threshold temperature, and N/N_1 is slightly temperature-dependent, the Card 2/5/

Us on W was studied X

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temperature dependence $\ln n = f(\frac{1}{T})$ is determined by the evaporation heats of the ions from surface 1; Thus one finds $N/N_1 = \frac{(V-Y_w)(T_0 - T_{01})}{T_{01}(y_w - y_1)}$, where $\phi_{\rm W}$ is the work function of a pure tungsten surface, which is correct provided that $\gamma_{\rm kmin}$ + $\gamma \gg {\rm kT}$, where $\gamma_{\rm kmin}$ is the minimum of the local work function. In order to verify these theoretical results experimentally, a cylindrical capacitor was placed into an unsoldered bulb filled with Cs vapor and containing a tungsten thread, 100 microns in diameter and 14 cm long, which was fastened along its axis. Ions emitted from the central portion of the thread were collected by the measuring cylinder. The bulb was provided with taps containing metallic Cs and a Ba-Ti getter. The temperature of the threal was measured with an optical micropyrometer; at low temperatures, it was determined from the filament current. The temperature of the first thermostat was kept above that of the second which was used to calculate the vapor pressure of Cs. The ion current was measured with a mirror galvenometer of a sensitivity limit of 3-10-10 a/scale

unit. The temperature dependence of the ionization of Cs on W was studied X

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Dependence of the ...

in a Cs vapor pressure range of 9.10⁻⁹ to 5.10⁻⁴ mm Hg, with a change in the threshold temperature from 880 to 1450 %. Since the error due to the may be re-written as In TOT 1.1.1

may be re-written as $\ln n \approx L + \frac{1}{k} \left(\frac{1}{T} - \frac{1}{T} \right)$. Professor N. I. Ionov,

Professor A. I. Gubanov, and N. D. Potekhina are thanked for discussion. There are 5 figures and 12 references: 5 Soviet and 7 non-Soviet. The four most recent references to English-language publications read as folutows: W. B. Nattingham, Proc. of the Fourth International Conference on Ionization Phenomena in Gases (Uppsala, 17 - 21 August, 1959), 1, 486, 1960, R. C. Evans, Proc. Roy. Soc. A139, 604, 1933; J. B. Taylor, J. Languair, Phys. Rev. 44, 423, 1933; T. J. Killian. Phys. Rev. 27, 578, 1926.

ASSOCIATION: Fizikio-tekhnicheskiy institut im. A. F. Ioffe AN SSSR, Leningrad (Physicotechnical Institute imeni A. F. Ioffe, AS USSR, Leningrad)

SUBMITTED: Card 4/54

June 17, 1961

37071 s/057/62/032/004/017/017 B173/B102

26,2312

26.1640 AUTHORS:

Zandberg, E. Ya., Ionov, N. I., Paleyev, V. I., and

Tontegode, A. Ya.

TITLE:

Determination of thermionic emission constants from energy distribution curves for thermoelectrons and positive ions

PERIODICAL: Zhurnal tekhnicheskoy fiziki, v. 32, no. 4, 1962, 503 - 516

TEXT: For plane and coaxially cylindrical electrodes with homogeneous work function, expressions ("ideal" retardation curves) for the emission current are derived on the assumption of Maxwellian energy distribution, and extended to electrodes with inhomogeneous work function (experimental retardation curves). As the areas of different work function (spots) cannot be localized, only a qualitative consideration is possible. The contact potential field of the spots is regarded first as being compensated by the external field (independent emission of individual spots) and then as not being compensated. The mean work function of the cathode was determined from the saturation current at given temperature. An apparent contact potential difference, which can be determined from the experimental

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AUTHOR: Zandberg, E. Ya.

TITLE: Surface ionization on matals in an electric field

SOURCE: Zhurnal tekhnicheskoy fiziki, v. 33, no. 6, 1963, 743-747

TOPIC TAGS: surface ionization, field descrption, field ion emission

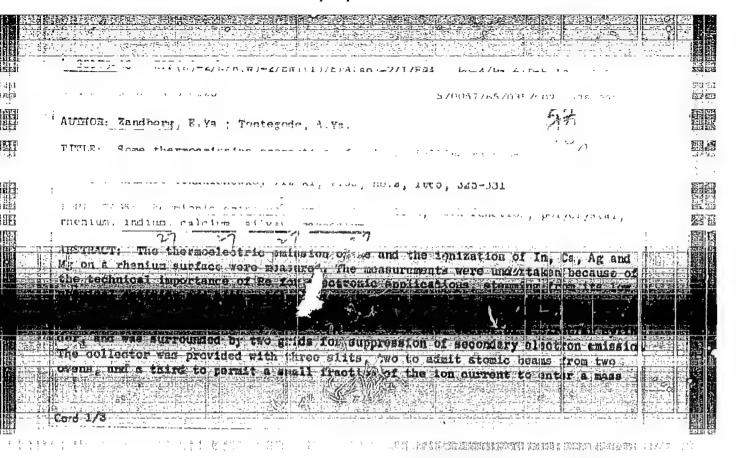
ABSTRACT: An improved expression is derived for the degree of surface ionization in an electric field as a function of the field strength. The work was undertaken in view of the importance of this relation not only for the theory of surface ionization, but for field descrition and ion emission as well, and because a rigorous derivation had not previously been given. The derivation follows the statistical method employed by LaN. Debretsov (Elektronnaya i ionnaya emissiya. Gos. izd. tekh-teor. literatury, 1952), but account is taken of the short range forces between the adsorbed atom and the surface (van der Waals forces, chemical forces, etc.). For the case of a very strong field, the result differs from that obtained for this case by Debretsov (ZhTF, 23, 417, 1953) by the presence in the exponent of a term taking account of the short range forces and the absence of the term eEx, where E is the field strength and x is the critical charge exchange distance. The author considers it likely that in the descrition of barium from

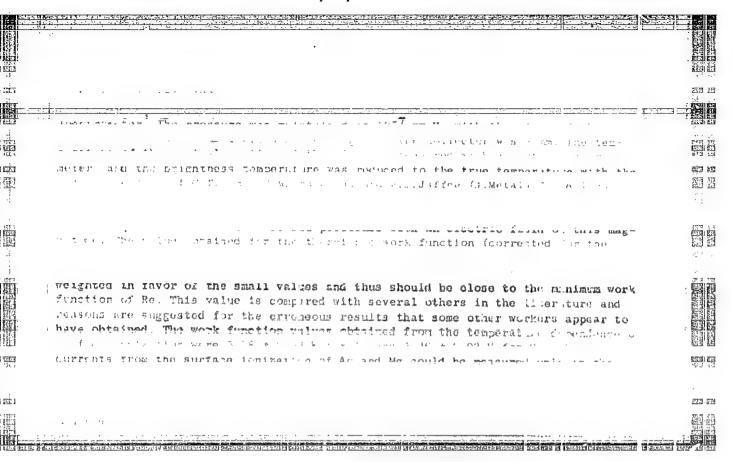
tungsten points the deviation from (J. Chem. Phys., 31, 341, 1959) is ausumption of the formation of dou N. I. Ionov for a discussion of the has: 20 formulas and 2 figures. ASSCCIATION: Fiziko-tekhnicheskiy (Physical-Technical Institute, AN S	ony charged be questions to institut im.	erium ions. Poeted in ti	"I thank ?	rofessor Orie.	the
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ACCESSION NE: AP4049048 \$/0057/64/034/011/2048/2055	
AUTHOR: Zandborg, E.Ya. Palnyav, V.I.	
TITIE: Surface ionization of In, K Rb and Cs atoms and CsCl. RbCl and K31 mole-	
cules, with formation of positive fons t	
p and the second	
SOURCE: Zhurnal tekhnicheskoy fiziki, v.34, no.11, 1964, 2048-2055	
TORIC TAGS: surface ionization, graphite, indium, potassium, rubidium, cerium, po-	
tassium compound, rubidium compound, cesium compound	ļ
ABSTRACT: The ionization of In, K, Rb, Cs, CsC1, RbC1 and KC1 on a graphite sur- face was measured at temperatures up to 2300°K. Graphite was chosen for investiga-	
tion because its electrical properties are intermediate between those of metals	
and semiconductors, spectroscopic grade graphite was employed in the form of 60 y	
1.2 mm strips from 200 to 700 micron thick, requiring up to 350 wattr for heating	
The temperature was measured with an optical pyrometer, and with a thermolouple at the lower temperatures. The thermical emission of the graphite was atable, with a	
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•	dependent of temperature above the threshold; the ionization coefficient as maken
	simm decreased somewhat with increasing temperature. The heberian of the amount to
	with respect to the ionization of alkali metals was very similar to that
	metal surfaces. The metal ion currents from the chloride molecules continued to the
	crease with increasing temperature. In the case of CaCl, a plot of the logarithm of
	the ion current versus the reciprocal temperature consisted of the circles.
-*	issues, or which that for the higher temperatures had the greater glave one account
	ion current at the higher temperatures is ascribed to increased dissociation of the
. ;	molecules. The relation between ion current and temperature is discussed in terms
	of the theory of surface reactions on perous materials, and it is concluded that
	the difference between the best of the bes
	the difference between the heat of dissociation on the surface and the heat of sub-
٠. ٠	tination from the surface lies between 0.6 and 1.0 eV for the different salts
.03	The authors thank Prof. L. Ivanov and M.D. Potekhina for discussing the results of he work. Orig. art. has 4 formulas and 9 figures.
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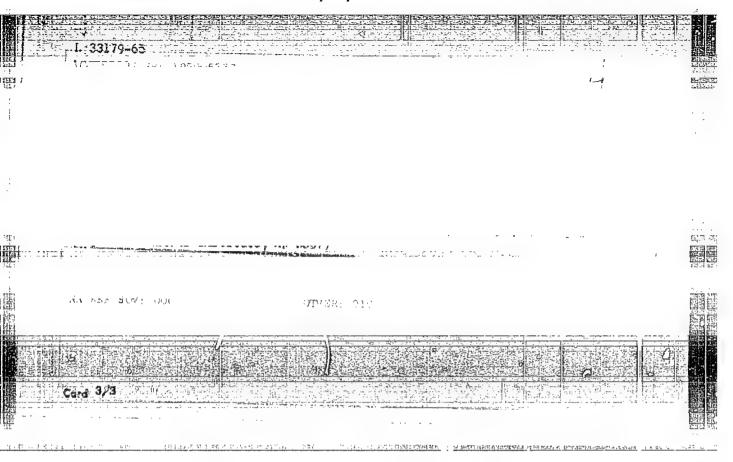


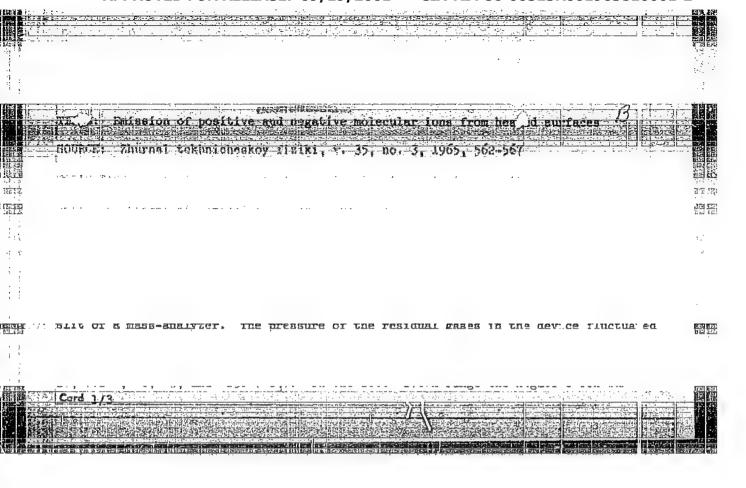


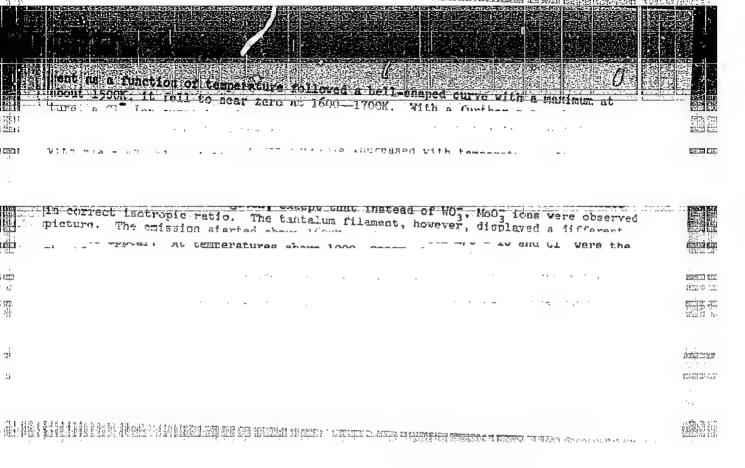
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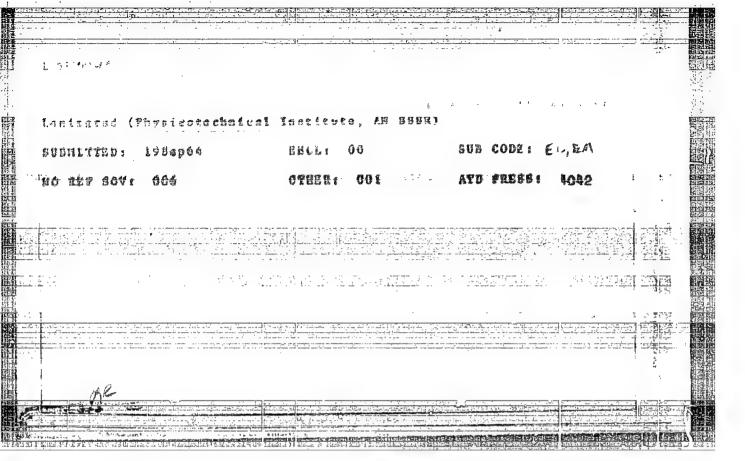
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		V.dtarodubtsev (Trudy FizLekim.inst. AT Uzb.SSR 2,6,1948), and the theories were found to be able to account for the data. The temperature dependences of the surface ionization currents from the alkali atoms were in malifacture assement with the presidence of	
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Tandberg. F. Fall Falevey, V. I. TITLE: Inherent thermionic emission of inothenum hexaboride and surface ionization of cesium atoms on it SOURCE: Zhurnel tekhnicheskoy fiziki, v. 35, no. 7, 1965, 1308-1311 TOPEC TAGGE therminate outsains inherent therminate emicaine icalizat on, cathode curiacs indistrict, surface artivation, stom ABSTRACTE An investigation was made of the surface ionization of Ca atoms on a cathode made of Lang. The use of compressed cathodes made it possible to enclude the influence of backing. Mass-spectrometric methods were used to permit observation of emission of the cathode and to make it possible to measure the temperature dependence of the thermoelectron current for use in determining the thermoelectron work function from the sema numbers soletin from which the ion current was Card 1/3

Were drawn: 1) The activated cathods probably has foreign inclusion and nonactivated surface sections on which the work function may exceed 3.9 v. 2 At 7 1400K, simultaneously with the rise of Cs current, the current of inherent the moemission of Lao also appears and at 1 v. 1600K the current of La eppears. Since the ionization potential of ignthanum v. 2 501 v. it is probable at at the main pertoof the lauthanum atoms evaporating from the surface are desorbed in the atomic state and not in the ionic. The intensity of the Lainthanum atoms evaporating from the surface are desorbed in the atomic state and not in the ionic. The intensity of the Lainthanum atoms evaporating from the surface are desorbed in the atomic state and not in the ionic. The intensity of the Lainthanum atoms evaporating from the surface are desorbed in the atomic state and not in the ionic. The intensity of the Lainthanum atoms evaporating from the surface are desorbed in the atomic state and not in the ionic. The intensity of the Lainthanum atoms evaporating from the surface are desorbed in the atomic state and not in the ionic. The intensity of the Lainthanum atoms evaporating from the surface are desorbed in the atomic state and not in the ionic. The intensity of the Lainthanum atoms evaporating from the surface are desorbed in the atomic state and not in the ionic. The intensity of the Lainthanum atoms evaporating from the surface are desorbed in the atomic state and not in the ionic.



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L 2303-66 ENT(1)/ENT(n)/ETC/EPF(n)-2/EID(E)/ENA(d)/EPA(W)-2/T/ENP(t)/ENP(t)/ENP(t) AP5020741 UR/0057/65/035/008/1501/1503 ACCESSION NRI AUTHOR: Zandberg, E. Ya.; Tontegode, A. Ya. Thermionic emission constants of molybdenum, tantalum, and tungsten wires TITLE: 27 SOURCE: Zhurnal tekhnichcskoy fiziki, v. 35, no. 6, 1965, 1501-1503 TOPIC TAGS: work function, thermionic emission, surface ionization, polycrystal, molybdonum, tantalum, tungsten ABSTRACT: The authors have measured the thermionic and surface ionization work functions of 100 to 150 micron diameter polycrystalline Ta, Mo, and W wires with an apparatus that they have described elsewhere (ZETF, 35, 149, 1965). Tungster was measured as a control. The thermionic work functions were derived from Richardson curves and the surface ionization work functions were determined from the temperature dependence of the surface ionization current of indium. The temperatures were measured with an optical micropyroseter and were corrected to true values by means of published tables. The Mc, Te, and W wires were annealed at 24000, 26000, and 27000K, respectively. This next treatment was sufficient to stabilize the thermionic emission properties and to eliminate self-emission of impurity sikali metal ions. The residual gas pressure was approximately 10-7 mm Hg. Card 1/2

L 2303-66 ACCESSION NR: AP5020741 The measured thermionic work functions of Ta, No, and W were 4.33, 4.33, and 4.48 V, respectively; the corresponding surface ionization work functions were 4.88, 5.02, and 5.14 V. The probable errors of these work functions range from 0.03 wo 0.07 V. The values found for the work functions differ considerably from those reported by Kh.Khadzhimukhamedov and G.N.Shuppe (Izv. AN Uzb. SSR, Ser. fiz.-mail. nauk, 2, 55, 1957) . This discrepancy is ascribed to the use by Khadzhiaukhamadov and Shuppe, of easily ionized alkali metals to measure the surface ionization work functions. Ta and (from earlier work) Re wires have much more stable thermionic emission proporties than No or W wires. Orig: art. has: 1 formula, 1 figure, and 1 table. ASSOCIATION: Fiziko-tekhnichuskiy institut im. A.F. loffe AN SSSS, Leningred (Physico-technical Institute: AN 888R) . 44,55. ENCL: 00 SUBMITTED: 2LJan65 SUE CODE: 89. OTHER: HR REF SOV: Micro wires BVK

L 2304-66 EWT(m)/EPF(c)/EWA(d)/T/ JD/ ACCESSION NR: AP5020742	/ли	4 2 .
AUTHOR: Zandberg, E. Ya.: Ionov, N. 1.77 TITLE: Mass spectrometric determination positive ions in sublimation of polycrysta	of the heat of vaporization	n of atoms find antalum, and
SOURCE: Zhurnal tekhnicheskoy fiziki, variance of sublimation, vacuum sumass spectometer, rhenium, tungsten, tantal ABSTRACT: The authors have directly determed of atoms and ions from polycrystalline suma, and Mo. These measurements are said to it. The samples were 45 mm long 100 to 150 in the common axis of three cylindrical gride applied. Positivo ions leaving the surface egative potentials on the cylindrical gride ass spectremeter. When atoms were being in at 1/3	ined the vaporization energy to the first direct determicron polycrystalline wirks to which appropriate not	function, gies La and metals Rs, W minations of cos located

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positive potentials on the grids. The atoms diffused into a chamber where they were ionized by an electron beam and the resulting ion flux was measured with the mass spectrometer. The use of a mass spectrometer to determine the composition of the sublimed gas is considered essential. When the residual gas pressure in the apparatus was 10-7 mm Hg; only atoms and atomic ions were found; when the pressure was (1-5) x 10-6 mm Hg, oxide molecules and molecular ions were also present. The temporature of the sample was determined with an optical micropyrometer, and the position of the sample and the electrode system was monitored by measuring the surface ionization of indium. The samples were subjected to a prolonged preliminary heating at the highest temperature employed in the measurements. The vaporization energies were determined from the temperature dependences of the fluxes. The thurmodynamic theory of this determination is derived and the type of average over the different crystallographic faces to which it leads is discussed. It is not possible directly to test the consistency of the data by means of the Schottky relation $L_a - L_i = e(W - V)$, where W is the work function and V is the ionization potential, because the different quantities are averaged differently. The question of averages is discussed at some length, and inequalities are derived that the measured values of L_a , L_i , and W should (and do) satisfy. The statistical error of the vaporization energy measurements was approximately 5%. A systematic error as great as 4% is possible in the Ho and Ta temperature measurements. The values ob-

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AUTHOR: Zandborg, E. Ya.; Paleyev, V.I. ORG: Physico-technical Institute im. A.F. Ioffe, AN SSSR, Leningrad (Fiziko-
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TITLE: Surface 2002-2098
SOURCE: Zhurnal tekhnicheskoy fiziki, v. 35, no. 11, 1965, 2092-2098
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TOPIC TAGS: surface ionization, crystal surface, semiconductor crystal, silicon, alkali metal, indium, work function, thermionic emission, atom, particle from alkali metal, indium, work function of constant of Cs, K, Na, in, alkali metal, indium, work function from and the ionization of Cs, K, Na, in, alkali metal, indium, work function, thermionic emission from and the ionization of Cs, K, Na, in, alkali metal, indium, work function, thermionic emission from and the ionization of Cs, K, Na, in, alkali metal, indium, work function, thermionic emission from and the ionization of Cs, K, Na, in, alkali metal, indium, work function, thermionic emission from and the ionization of Cs, K, Na, in, alkali metal, indium, work function, thermionic emission from and the ionization of Cs, K, Na, in, alkali metal, indium, work function, thermionic emission from and the ionization of Cs, K, Na, in, alkali metal, indium, work function, thermionic emission from and the ionization of Cs, K, Na, in, alkali metal, indium, work function, thermionic emission from and the ionization of Cs, K, Na, in, alkali metal, indium, work function, thermionic emission from and the ionization of Cs, K, Na, in, alkali metal, indium, work function, thermionic emission from and the ionization of Cs, K, Na, in, alkali metal, indium, work function, the individual emission from an alkali metal, indium, work function, alkali metal, indium, alkali metal, indium, work function, alkali metal, indium, work function, alkali metal, indium,
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Phys., 28, 1510, 1/57); The Co ston beans were obtained by raduction of the chloride with callium; the remaining alomic beams were obtained by evaporating the metals. An iron oven was employed for the Li evaporation, and fused quartz ovens were used for the other metals. The atomic beam intensities at the crystal ranged from 107 atom/cm2sec for Cs and K to 5 x 109 atom/cm2 sec for In. The silicon crystal was outgassed and annealed at 1550-1690°K before the measurements. During the anneal the room temporature resistivity of the silicon crystal decreased by a factor 2 and thereafter remained stable. The length of entrance slit of the mass spectrometer was 1 mm; ions were accordingly admitted only from the central portion of the crystal where the temperature was uniform. The pressure in the stainless steel chamber was maintained below 10⁻⁷ mm Hg during the measurements. The thermoelectronic work function, derived from Richardson plots, was found to be 4.94 ± 0.05 V; it was incependent of the field strength at the crystal surface over the range from 75 to 1250 V/cm. No temperature dependence of the surface ionization currents of Cs and K was found in the temperature range investigated; the surface ionization thresholds for these metals occur at lower temperatures. The surface ionization currents of Na, Li, and In varied with temperature in accord with the Saha-Langmair equation, and all three metals gave the same value 4.9 V for the work function, within the experimental error of less than 0.1 V. Possible reasons are discussed for the large discrepancy between the thermoelectronic and surface ionization work functions and no satisfactory explanation is found. Further investigation is necessary.

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CIA-RDP86-00513R001963810001-2

ACC NR: AP7008115

SOURCE CODE: UR/0020/67/172/004/0835/0888

AUTHOR: Zandberg, E. Ya.; Rasuley, U. Kh.; Shustrov, B. N.

ORG: Physicotechnical Institute im. A. F. Ioffe, Acedemy of Sciences, SSSR (Fiziko-tekhnicheskiy institut Akademii nauk SSSR)

TITLE: Thermionic emission of positive ions of certain organic compounds from tungsten oxides

SOURCE: AN SSSR. Doklady, v. 172, no. 4, 1967, 885-888

TOPIC TAGS: thermionic emission, tungsten compound

ABSTRACT: Experiments were carried out on thermionic emission from tungsten oxides in a mass spectrometric apparatus in the presence of various organic compounds at 10-5 mm Hg. The following compounds produced thermions: diethylamine, phenol, aniline, trimethylhydrazine, acetone peroxide, several amino acids, and also acetic and formic acid. Most attention was devoted to the ionization of the first four compounds. The spectra of thermionic emission from tungsten oxides (at T \le 1100 \cdot K) and tungsten (at T \ge 2000 \cdot K) are tabulated. With the exception of aniline, ions representing products of surface reactions were observed in all cases. The results are in accord with previously advanced hypotheses on the formation of thermions by both catalytic dissociative ionization and formation of "heavy" ions in chemical surface reactions. The temperature dependence of thermionic currents from tungsten oxide

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UDC: 537.58 + 543,51

ACC NR: AP7008115

surfaces was determined; the bell-jar shape of the I = f(T) curves obtained indicated the simultaneous occurrence of ionization and dissociation of the particles on the surface. In the case of aniline, the I = f(T) function was exponential. It is noted in conclusion that the thermal ionization of organic compounds on the surface of solids may be used as a method of studying processes of heterogeneous catalysis. Authors thank N. I. Ionov for discussing the results and I. N. Bakulin for his assistance. The paper was presented by Academician Konstantinov, B. P., 13 Apr 66. Orig. art. has: 3 figures and 1 table.

SUB CODE: 07/ SUBM DATE: 11Apr66/ ORIG REF: 007/ OTH REF: 006

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L 34817-66 EWT(1)/EWT(m)/T/EWP(t)/ETI IJP(c) JD/JG/AT ACC NR: APG018719 SOURCE CODE: UR 0057/66/036/006/0963/0980 AUTHOR: Zandberg, E. Ya.; Tontegode, A. Ya. ORG: Physicotechnical Institute im. A.F. Ioffe, AN SSSR, Leningrad (Fiziko-tekhnicheskiy institut AN SSSR) TITLE: Rhenium thermcemitters, a survey SOURCE: Zhurnal tekhnicheskoy fiziki, v. 36, no. 6, 1966, 963-980 TOPIC TAGS: rhenium, thermionic emission, surface ionization, ion source, mass spectrometry, field emission, thermionic energy conversion, melting Point, WORK FUNCTION, REFRACTORY METAL ADSTRACT: In this survey article, which has a bibliography of 74 entries, the authors review the properties of rhenium with particular attention to its use as a thermionic emitter and as a medium for surface ionization and compare them with those of other refractory metals such as tungsten, molybdenum, and tantalum. The scope of the survey is indicated by the section and subsection headings: 1) Melting point; 2) Heat of vaporization and vapor pressure; 3) Crystal structure; 4) Mechanical propertios; 5) Electric conductivity; 6) Chemical properties, a) Reaction with carbon, b) Reaction with nitrogen, c) Reaction with oxygen, d) Reaction with water, e) Reaction with Alundum; 7) Spectral emissivity; 8) Thermionic emission; 9) Surface ionization work function; 10) Surface ionization of alkali halide molecules; 11) Examples of Card 1/2

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AUTHOR: Paleyev, V. I.; Karatayev, V. I.; Zandberg, E. Ya.

ORG: Physicotechnical Institute im. A.F. Ioffe, AN SSSR, Leningrad (Fiziko-tekhnich-eskiy institut AN SSSR)

TITLE: On the applicability of the Saha-Langmuir formula to the description of the temperature dependence of the positive ion current incident to surface ionization of atoms on silicon

SOURCE: Zhurnal tekhnicheskoy fiziki, v. 36, no. 8, 1966, 1459-1468

TOPIC TAGS: surface ionization, silicon single crystal, work function, thermionic emission, contact potential, Richardson equation, ION CURRENT

ABSTRACT: The authors have previously investigated the surface ionization of Na, Li, and In on a (111) face of a silicon single crystal (ZhTF, 35, 2092, 1965) and obtained from their results, with the aid of the Saha-Langmuir formula, the value 4.9 V for the work function of the (111) face of silicon. This value of the work function is much greater than the value 4.0 V obtained from Richardson plots. Possible hypothesized reasons for this discrepancy are discussed briefly and most are found to be unconvincing. To clarify this situation, measurements of the work function by different techniques were undertaken. The measurements were made on the (111) face of a p-type silicon crystal with a resistivity of about 1000 obm cm. Contact potential work

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L 45917-66 ACC NR: AP6028620 functions were derived from retarding potential curves of the thermoelectron emission current and of the positive ion current from surface ion mation of cesium by comparison with analogous curves obtained with tungsten and graphite emitters. The thermoelectron emission current was also measured, and work functions were derived both from Richardson plots and from the total emission current. The retarding potential curves showed that both the electrons and the positive ions had Maxwellian distributions with temperatures equal within the experimental error of 100° C to the temperature of the emitter. The contact potential work functions derived from the retarding potential curves were independent of temperature over the investigated range from 1100 to 1,600°K and wore equal, within the experimental error of about ± 0.1 V, to the value previously obtained with the aid of the Saha-Langmuir equation from the temperature dependence of the surface ionization. The total emission current work function was equal to the contect potential work function of 1600°K but had a temperature derivative of 6 x 10° degree. The Richardson plot gave the previous low value for the work function (4.07 ± 0.05 V). From the agreement between the contact potential and surface ionization work Inctions it is concluded that the Saha-Langmuir equation correctly describes the ternerature dependence of the surface ionization of Na, Li, and In on silicon. Fossible reasons for the low value of the Richardson plot work function are briefly discussed, but none is selected as the most likely. The authors thank N.I. Ionov and H.D. Potekhin for discussions. Orig. art. has: 5 formulas, 6 figures and 1 table. OTH REF: 800 ORIG. REF: 011 SUBM DATE: 03 Jan66 SUB CODE: mjs 2/2 Card